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(12) **United States Design Patent**
**Boukai et al.**

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(54) **THERMOELECTRIC SMARTWATCH**

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USPC ........................................................ **D14/344**

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CPC .. A41D 1/002; G06F 1/04; G06F 1/08; G06F 1/10; G06F 1/14; G06F 1/1626; G06F 1/1628; G06F 1/163; G06F 1/1635; G06F 1/3203; G06Q 20/10; G06Q 20/12; G06Q 20/108; G06Q 20/145; H04B 1/3833; H04B 1/385; H04B 1/3888; H04M 1/02; H04M 1/03; H04M 1/04; H04M 1/05; H04M 1/667; H04M 1/6058; Y02B 60/1217
See application file for complete search history.

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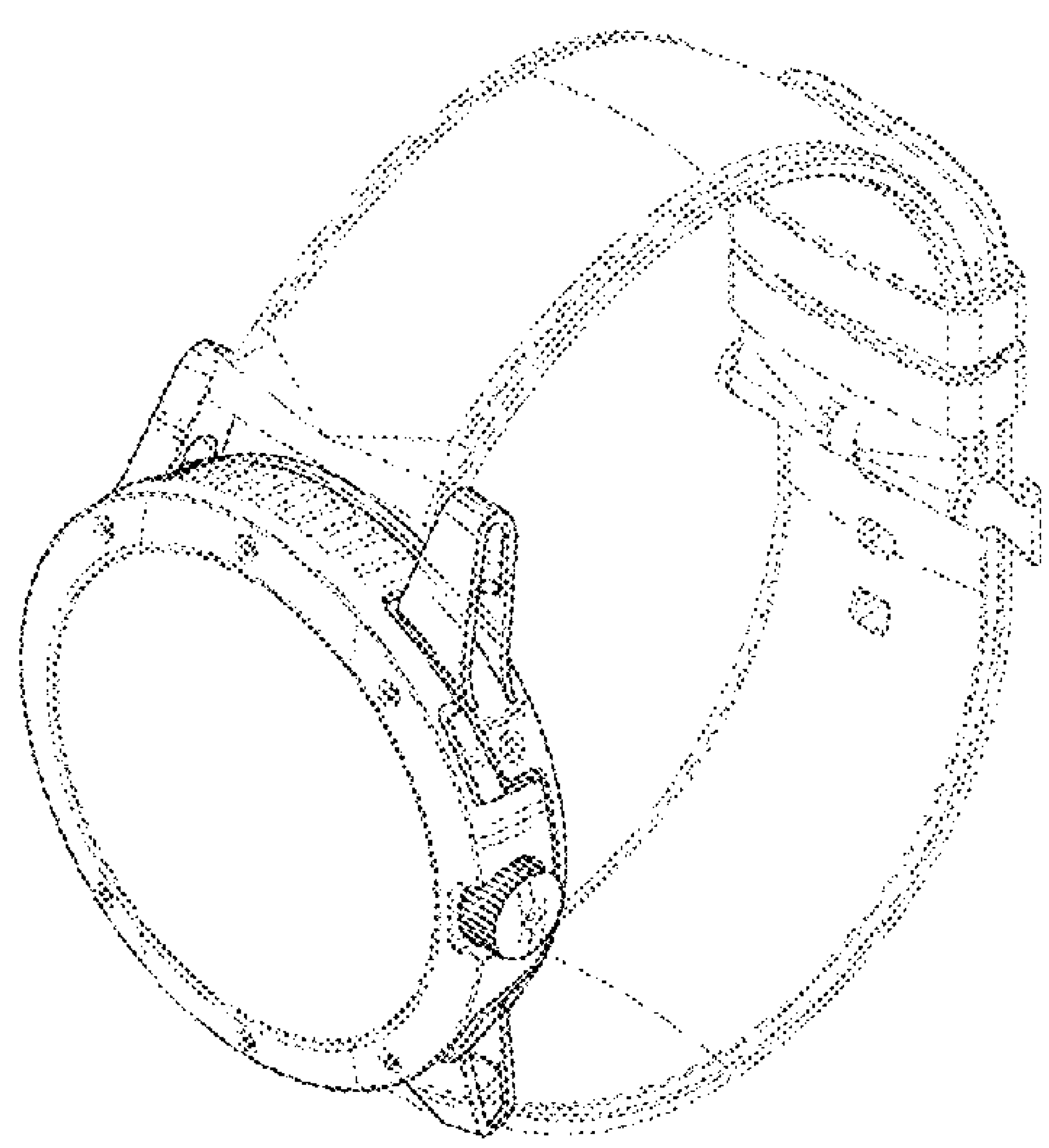
(57) **CLAIM**

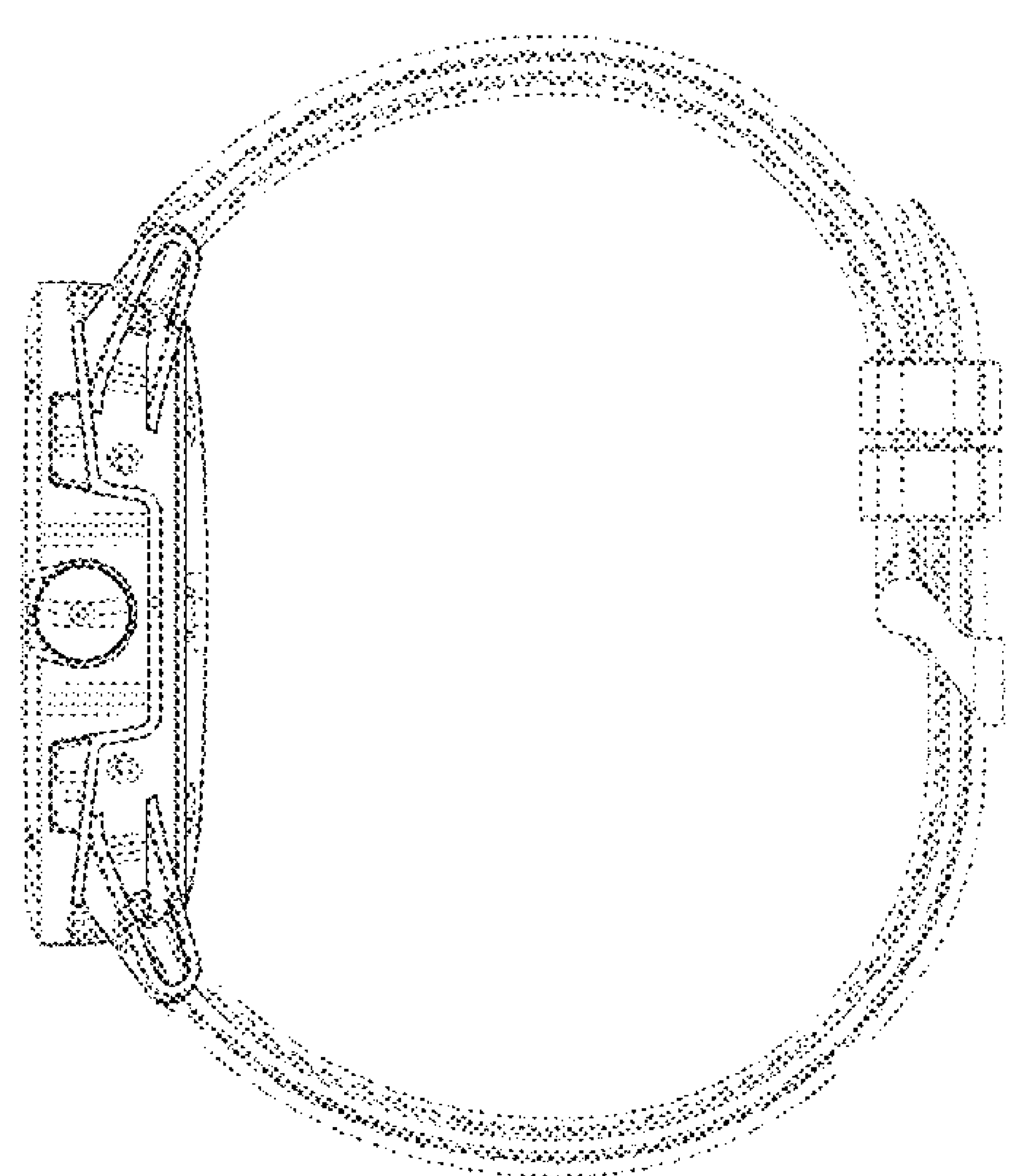
The ornamental design for a thermoelectric smartwatch, as shown and described.

**DESCRIPTION**

FIG. **1** is a top perspective view of a thermoelectric smartwatch in accordance with the present design;
FIG. **2** is a front view of the thermoelectric smartwatch;
FIG. **3** is a back view of the thermoelectric smartwatch;
FIG. **4** is a right side view of the thermoelectric smartwatch;
FIG. **5** is a left side view of the thermoelectric smartwatch;
FIG. **6** is a top view of the thermoelectric smartwatch; and,
FIG. **7** is a bottom view of the thermoelectric smartwatch.
The broken lines shown in FIGS. **1-7** in the drawings depict portions of the thermoelectric smartwatch that form no part of the claimed design.

**1 Claim, 7 Drawing Sheets**





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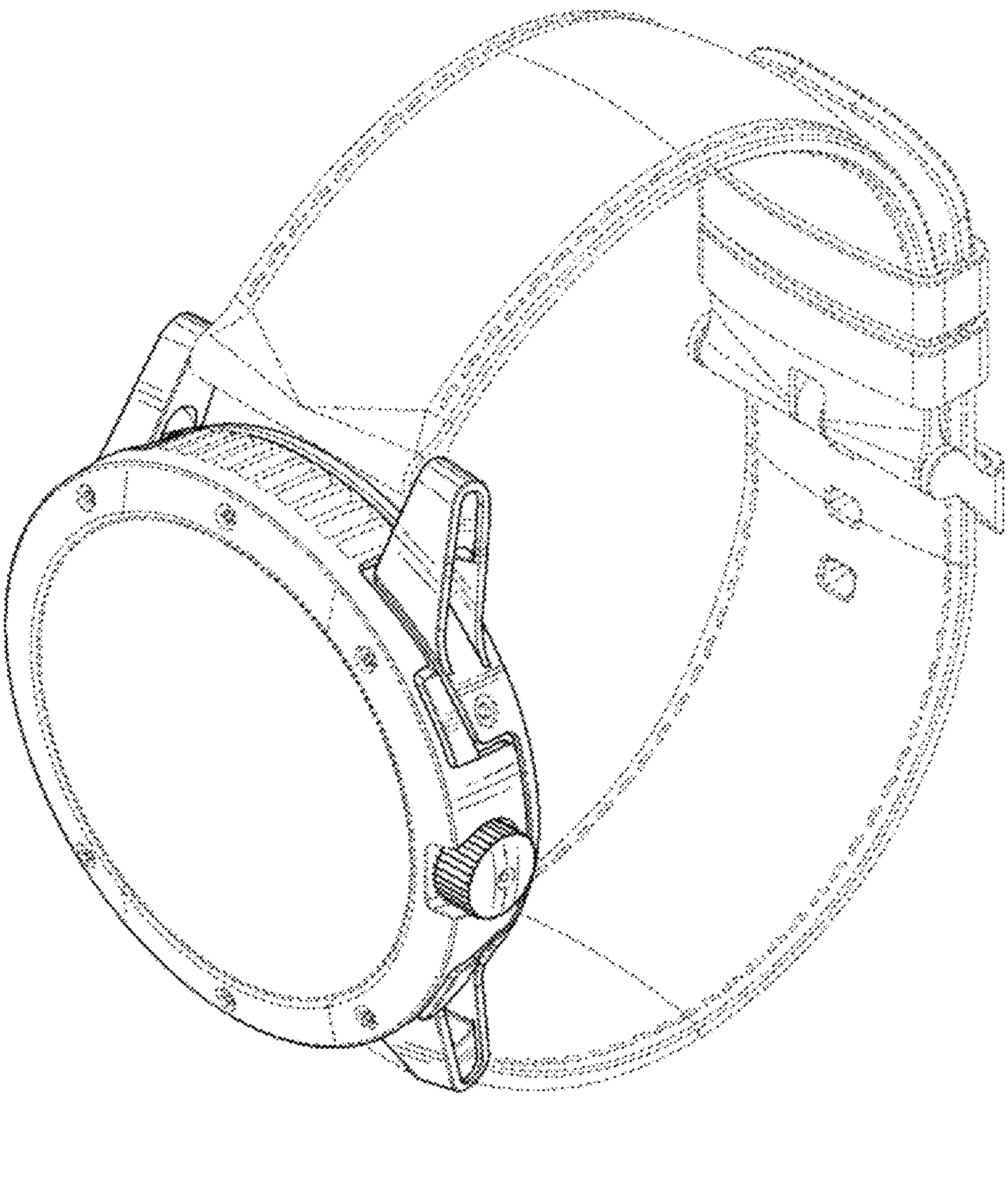

FIG. 1

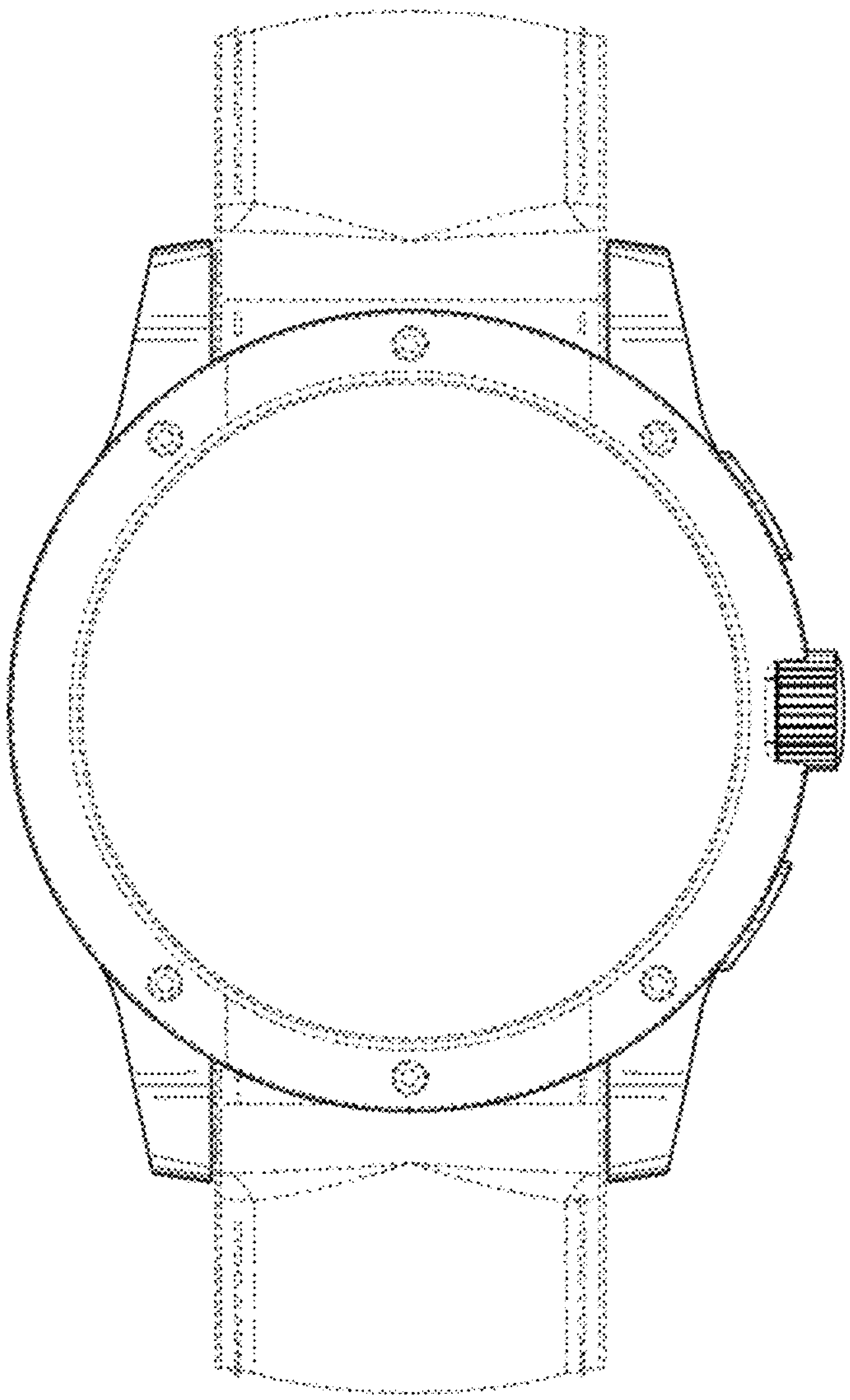

FIG. 2

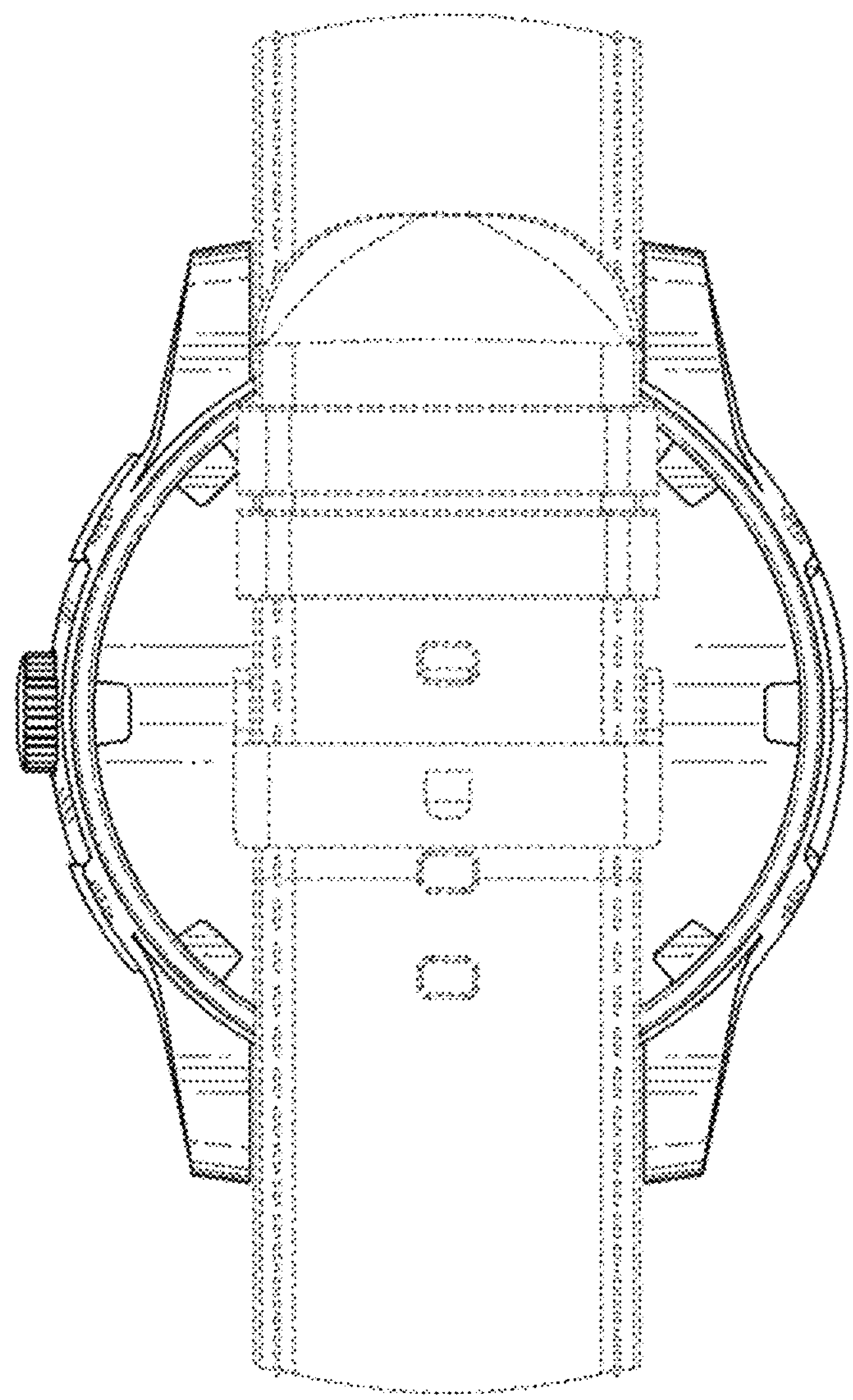

FIG. 3

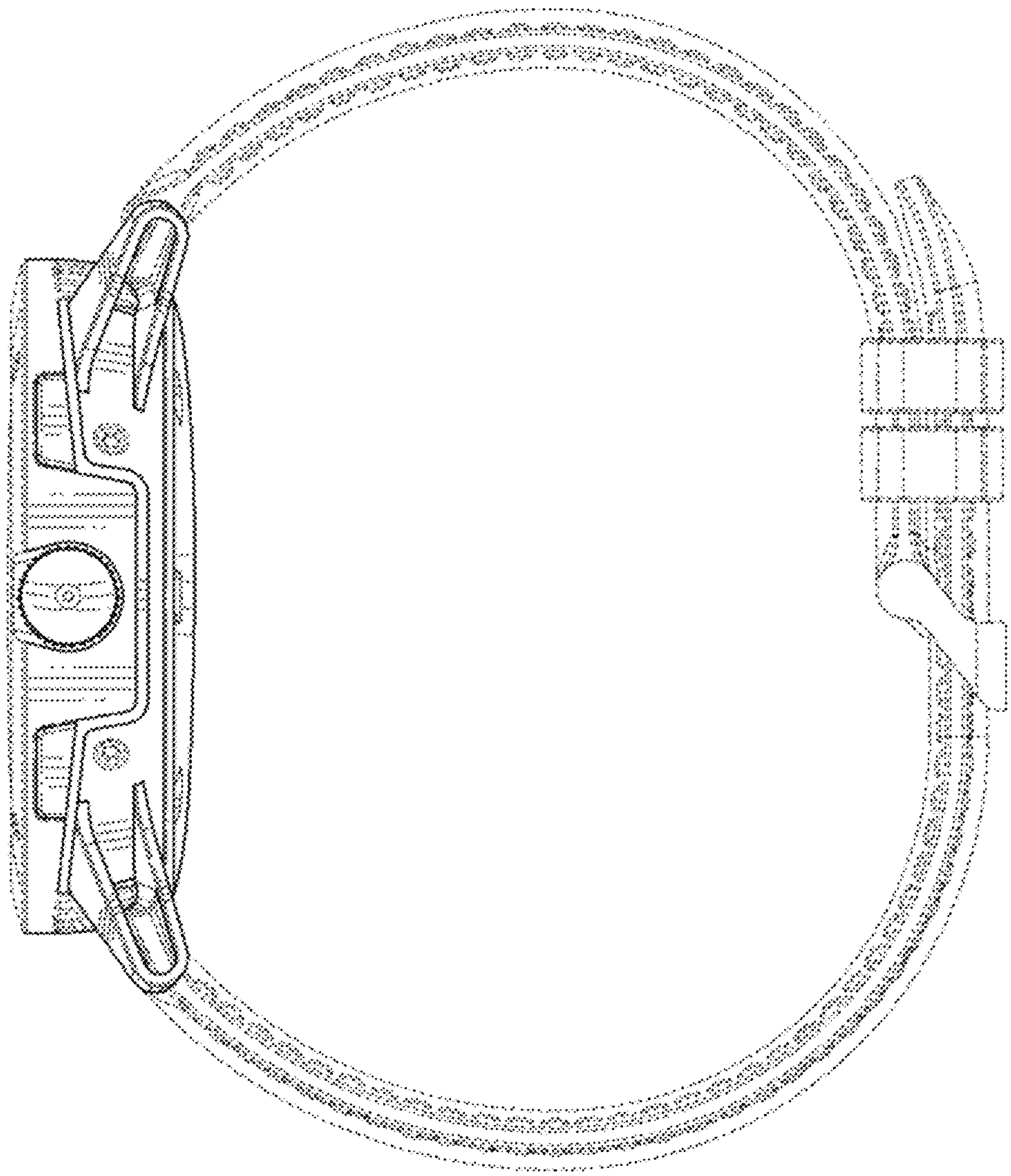

FIG. 4

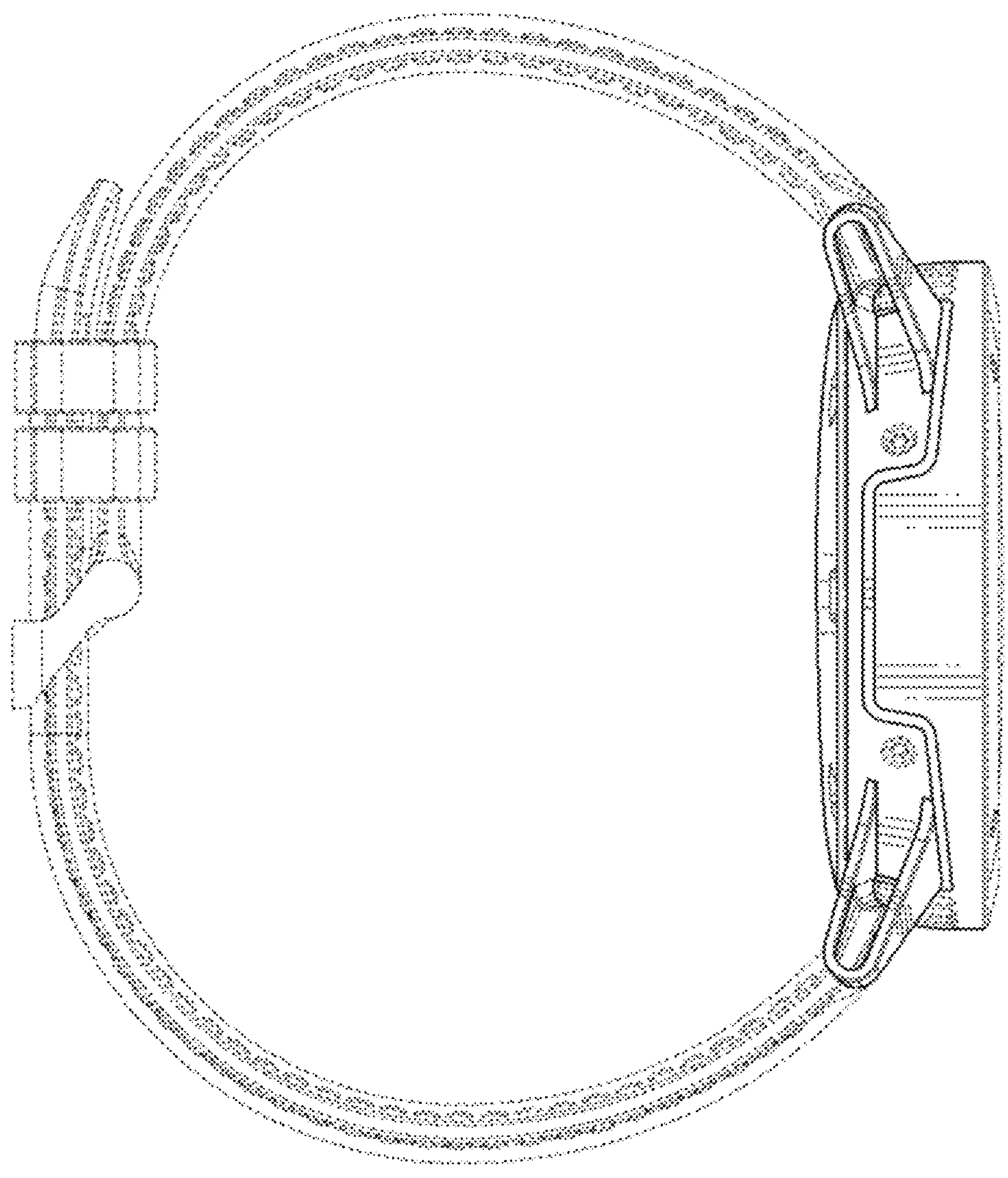

FIG. 5

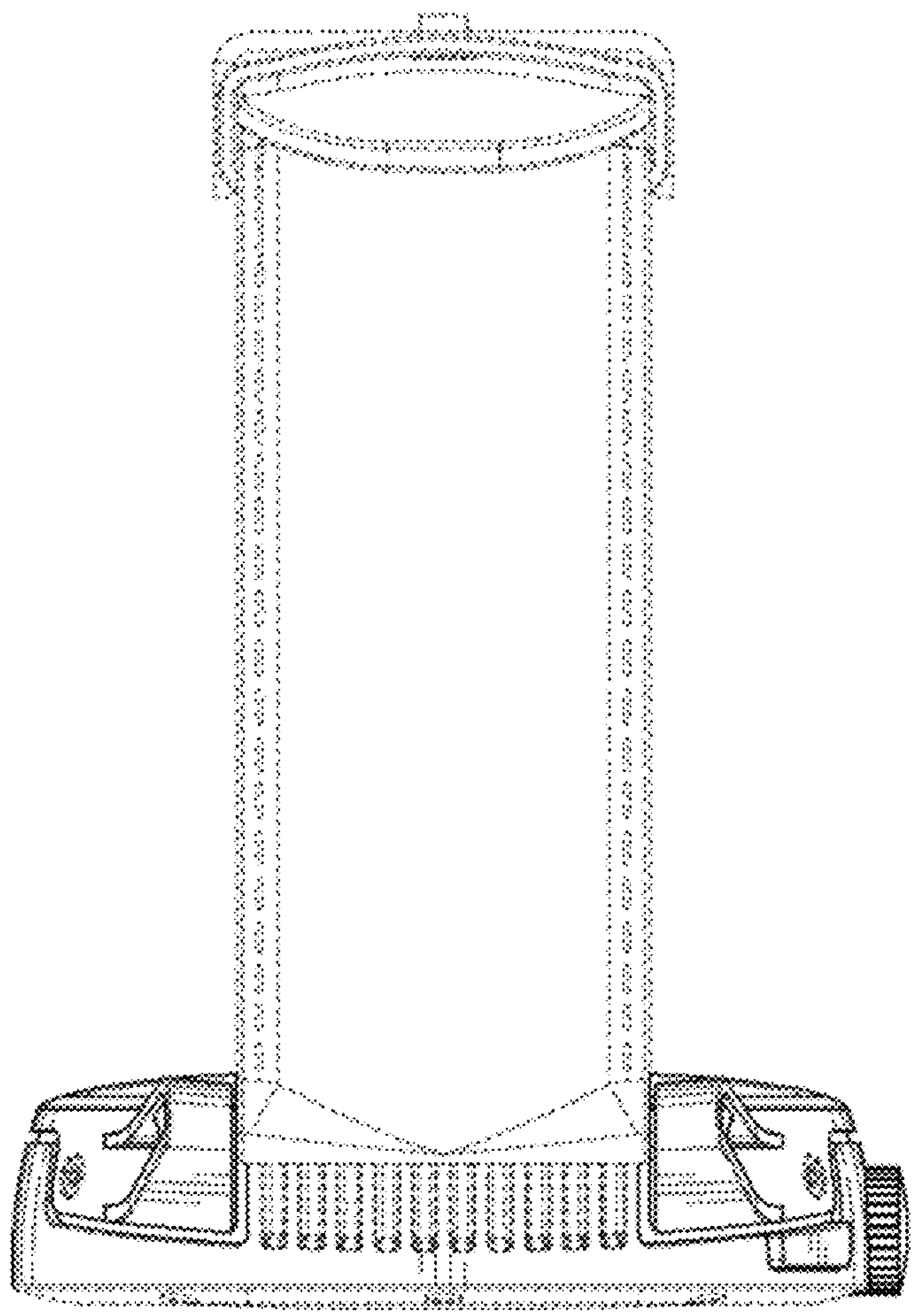

FIG. 6

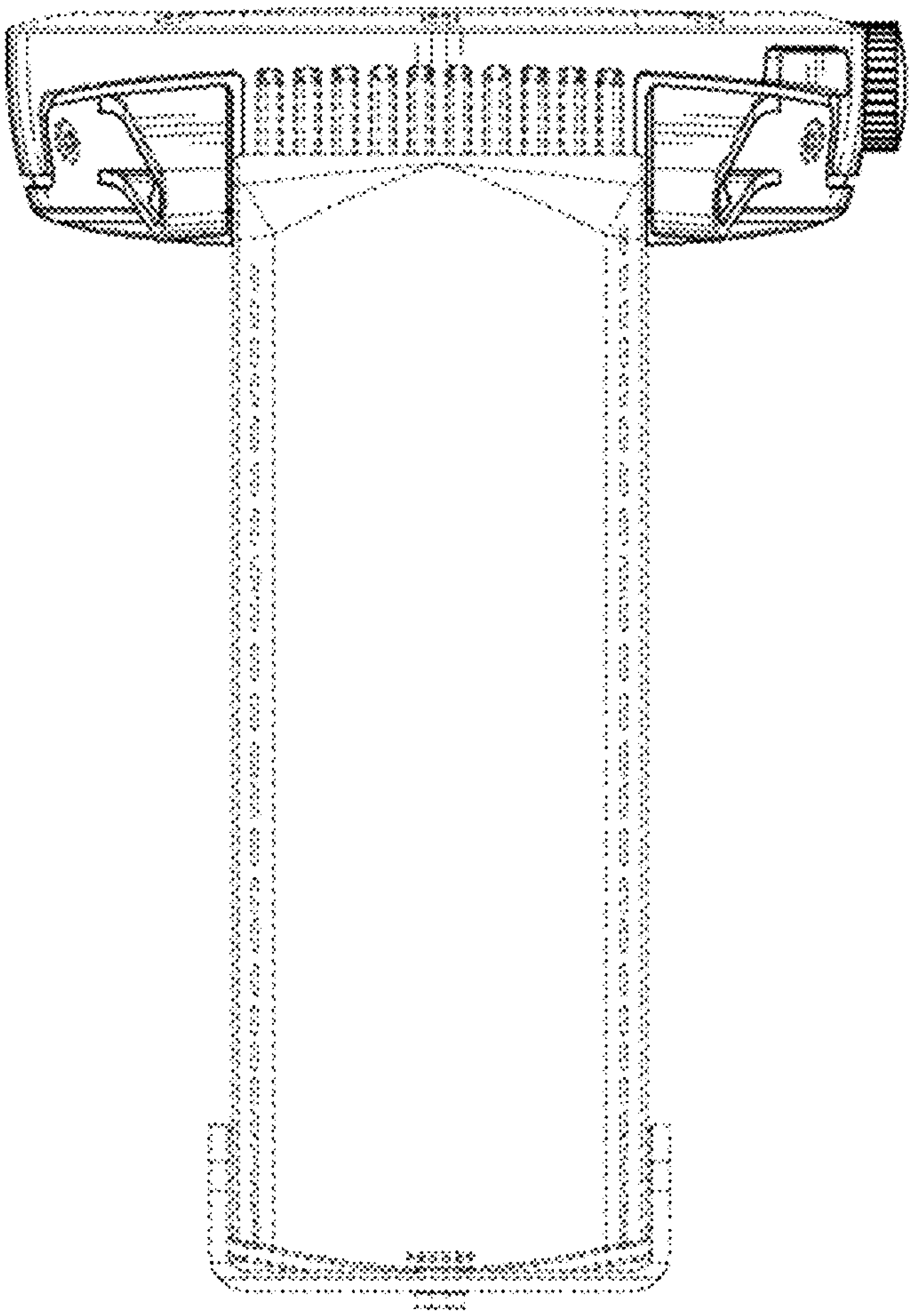

FIG. 7